



BV _{DSX} / BV _{DGX}	R _{DS(on)} (max)	I _{DSS} (min)	Package
250V	2.5Ω	400mA	SOT-223

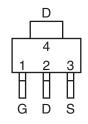
Features

- High Breakdown Voltage: 250V
- On-Resistance: 2.5Ω max. at 25°C
- Low V_{GS(off)} Voltage: -1.4 to -3.1V
 High Input Impedance
- Small Package Size: SOT-223

Applications

- Current Regulator
- Normally-On Switches
- Solid State Relays
- Converters
- Telecommunications
- Power Supply

Package Pinout



Description

The CPC3902 is a 250V, N-channel, depletion-mode, metal oxide semiconductor field effect transistor (MOSFET) built upon a proprietary third generation vertical DMOS process that realizes world-class, high voltage performance in an economical silicon gate process. This vertical DMOS process yields a robust device with high input impedance for power applications.

As with all MOS devices, the FET structure prevents thermal runaway and thermal-induced secondary breakdown, which makes the CPC3902 ideal for use in high-power applications.

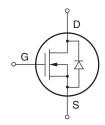
The CPC3902 is a highly reliable FET device that has been used extensively in IXYS Integrated Circuits Division's Solid State Relays for industrial and telecommunications applications.

The CPC3902 is available in the SOT-223 package.

Ordering Information

Part #	Description
CPC3902ZTR	SOT-223: Tape and Reel (1000/Reel)

Circuit Symbol







Absolute Maximum Ratings @ 25°C

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Parameter	Ratings	Units		
Drain-to-Source Voltage	250	V		
Gate-to-Source Voltage	±15	V		
Pulsed Drain Current	400	mA		
Total Package Dissipation ¹	1.8	W		
Operational Temperature	-55 to +110	°C		
Junction Temperature, Maximum	+125	°C		
Storage Temperature	-55 to +125	°C		

¹ Mounted on 1"x1" 2 oz. Copper FR4 board.

Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.

Typical values are characteristic of the device at +25°C, and are the result of engineering evaluations. They are provided for information purposes only, and are not part of the manufacturing testing requirements.

Thermal Characteristics

Device	Parameter	Symbol	Rating	Units	
CPC3902Z (SOT-223)	Junction to Case	θ_{JC}	14	°C/W	
	Junction to Ambient	θ_{JA}	55	0/11	

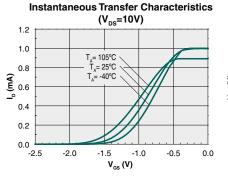
Electrical Characteristics @ 25°C (Unless Otherwise Noted)

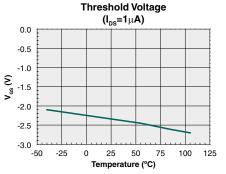
Parameter	Symbol	Conditions	Min	Тур	Max	Units
Drain-to-Source Breakdown Voltage	BV _{DSX}	V _{GS} = -5.5V, I _D =100µA	250	-	-	V
Gate-to-Source Off Voltage	V _{GS(off)}	V _{DS} = 15V, Ι _D =1μΑ	-1.4	-	-3.1	V
Change in $V_{GS(off)}$ with Temperature	dV _{GS(off)} /dT	V _{DS} = 15V, I _D =1µA	-	-	4.5	mV/°C
Gate Body Leakage Current	I _{GSS}	V _{GS} =±15V, V _{DS} =0V	-	-	100	nA
Drain-to-Source Leakage Current	I _{D(off)}	V _{GS} = -5.5V, V _{DS} =250V	-	-	1	μΑ
Saturated Drain-to-Source Current	I _{DSS}	V _{GS} = 0V, V _{DS} =15V	400	-	-	mA
Static Drain-to-Source On-State Resistance	R _{DS(on)}		-	-	2.5	Ω
Change in R _{DS(on)} with Temperature	dR _{DS(on)} /dT	V _{GS} = 0V, I _D =300mA, V _{DS} =10V	-	-	2.5	%/°C
Forward Transconductance	G _{fs}	I _D = 200mA, V _{DS} = 10V	400	-	-	mmho
Input Capacitance	C _{ISS}	V _{GS} = -3.5V		230		
Common Source Output Capacitance	C _{OSS}	V _{DS} = 20V	-	16	-	pF
Reverse Transfer Capacitance	C _{RSS}	f= 1MHz		9.5	1	
Source-Drain Diode Voltage Drop	V _{SD}	V _{GS} = -5V, I _{SD} =150mA	-	0.72	1	V

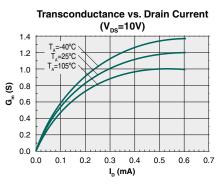


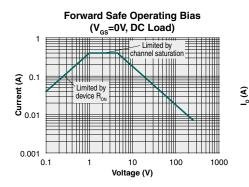
CPC3902

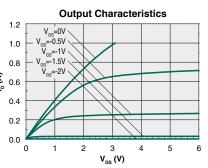
PERFORMANCE DATA*

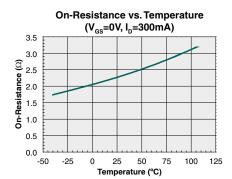


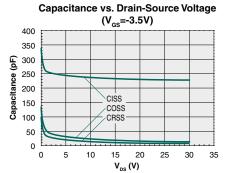


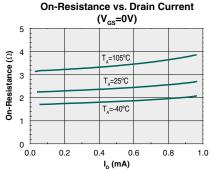


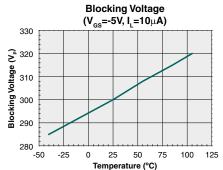


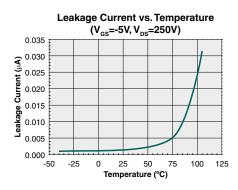












*Unless otherwise noted, data presented in these graphs is typical of device operation at 25°C. For guaranteed parameters not indicated in the written specifications, please contact our application department.

R04



Manufacturing Information

Moisture Sensitivity

All plastic encapsulated semiconductor packages are susceptible to moisture ingression. IXYS Integrated Circuits classifies its plastic encapsulated devices for moisture sensitivity according to the latest version of the joint industry standard, IPC/JEDEC J-STD-020, in force at the time of product evaluation. We test all of our products to the maximum conditions set forth in the standard, and guarantee proper operation of our devices when handled according to the limitations and information in that standard as well as to any limitations set forth in the information or standards referenced below.

Failure to adhere to the warnings or limitations as established by the listed specifications could result in reduced product performance, reduction of operable life, and/or reduction of overall reliability.

This product carries a **Moisture Sensitivity Level (MSL)** classification as shown below, and should be handled according to the requirements of the latest version of the joint industry standard **IPC/JEDEC J-STD-033**.

Device	Moisture Sensitivity Level (MSL) Rating	
CPC3902Z	MSL 1	

ESD Sensitivity



This product is ESD Sensitive, and should be handled according to the industry standard JESD-625.

Soldering Profile

Provided in the table below is the **IPC/JEDEC J-STD-020** Classification Temperature (T_c) and the maximum dwell time the body temperature of these surface mount devices may be (T_c - 5)°C or greater. The Classification Temperature sets the Maximum Body Temperature allowed for these devices during reflow soldering processes.

Device	Classification Temperature (T _c)	Dwell Time (t _P)	Max Reflow Cycles
CPC3902Z	260°C	30 seconds	3

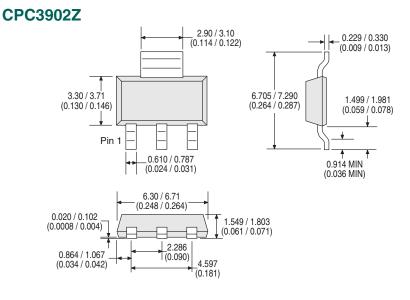
Board Wash

IXYS Integrated Circuits recommends the use of no-clean flux formulations. Board washing to reduce or remove flux residue following the solder reflow process is acceptable provided proper precautions are taken to prevent damage to the device. These precautions include but are not limited to: using a low pressure wash and providing a follow up bake cycle sufficient to remove any moisture trapped within the device due to the washing process. Due to the variability of the wash parameters used to clean the board, determination of the bake temperature and duration necessary to remove the moisture trapped within the package is the responsibility of the user (assembler). Cleaning or drying methods that employ ultrasonic energy may damage the device and should not be used. Additionally, the device must not be exposed to halide flux or solvents.

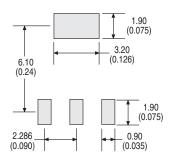




Mechanical Dimensions

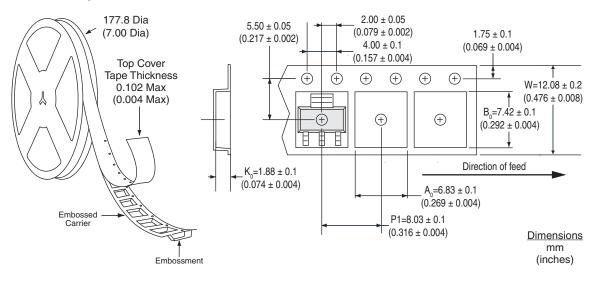


PCB Land Pattern



Dimensions mm MIN / mm MAX (inches MIN / inches MAX)

CPC3902ZTR Tape & Reel



For additional information please visit our website at: www.ixysic.com



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